

## DC COMPONENTS CO., LTD.

### RECTIFIER SPECIALISTS

UF2A THRU UF2K

# TECHNICAL SPECIFICATIONS OF SURFACE MOUNT ULTRA FAST RECTIFIER VOLTAGE RANGE - 50 to 800 Volts CURRENT - 2.0 Amperes

#### **FEATURES**

- \* Ideal for surface mounted applications
- \* Low leakage current
- \* Glass passivated junction

#### MECHANICAL DATA

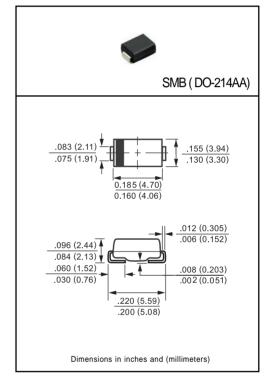
\* Case: Molded plastic

\* Epoxy: UL 94V-0 rate flame retardant \*Terminals: Solder plated, solderable per MIL-STD-750, Method 2026

\* Polarity: As marked \* Mounting position: Any \* Weight: 0.093 gram

#### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%.



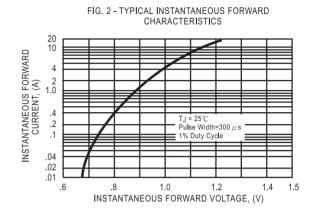
		SYMBOL	UF2A	UF2B	UF2D	UF2G	UF2J	UF2K	UNITS
Maximum Recurrent Peak Reverse Voltage		VRRM	50	100	200	400	600	800	Volts
Maximum RMS Voltage		VRMS	35	70	140	280	420	560	Volts
Maximum DC Blocking Voltage		VDC	50	100	200	400	600	800	Volts
Maximum Average Forward Rectified Current at TA = 75 °C		lo	2.0						Amps
Peak Forward Surge Current 8.3 ms single half sine-wave superimposed on rated load (JEDEC Method)		IFSM	60						Amps
Maximum Instantaneous Forward Voltage at 2.0A DC		VF		1.0		1.4	1.	.7	Volts
Maximum DC Reverse Current	@TA = 25°C	IR 10					uAmps		
at Rated DC Blocking Voltage	@Ta = 100°C		200						u,ips
Maximum Reverse Recovery Time (Note 3)		trr		50			100		nSec
Typical Thermal Resistance (Note 2)		RθJL	20					°C/W	
Typical Junction Capacitance (Note 1)		C1	30						pF
Operating and Storage Temperature Range		TJ,TSTG	-65 to + 175					۰c	

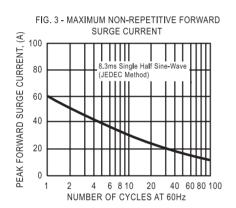
NOTES: 1. Measured at 1 MHz and applied reverse voltage of 4.0 volts.

- 2. Thermal Resistance (Junction to Ambient), 0.2x0.2in² (5X5mm²) copper pads to each terminal.
- 3. Test Conditions: IF=0.5A, IR=1.0A, IRR=0.25A.

#### RATING AND CHARACTERISTIC CURVES (UF2A THRU UF2K)

FIG. 1 - TYPICAL FORWARD CURRENT **DERATING CURVE** AVERAGE FORWARD CURRENT, (A) 2.5 2.0 1.5 1.0 Single Phase Half Wave 60Hz .5 Resistive or Inductive Load 0 0 50 25 75 100 125 150 175 AMBIENT TEMPERATURE, (°C)





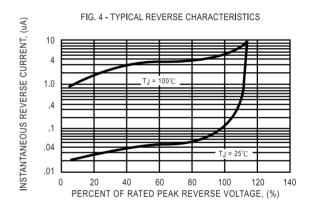


FIG. 5 - TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY FIG. 6 - TYPICAL JUNCTION CAPACITANCE TIME CHARACTERISTIC 200 50 Ω NONINDUCTIVE (pF) 100 NONINDUCTIVE +0.5A 60 JUNCTION CAPACITANCE, 40 D.U.T (+) 0 PULSE 20 25 Vdc GENERATOR (approx) -0.25 (NOTE 2) 10 OSCILLOSCOPE 6 (NOTE 1) INDUCTIVE 4 -1.0A 2 NOTES:1 Rise Time = 7ns max. Input Impedance = - SET TIME BASE FOR 1 megohm. 22 pF. → 1cm 50/100 ns/cm 2. Rise Time = 10ns max. Source Impedance = .1 .2 .4 1.0 2 4 10 20 40 100 50 ohms. REVERSE VOLTAGE, (V)

